# **Integrated Load Switch**

### **General Description**

This device is particularly suited for compact power management in portable electronic equipment where 2.5 V to 8 V input and 0.83 A output current capability are needed. This load switch integrates a small N–Channel power MOSFET (Q1) that drives a large P–Channel power MOSFET (Q2) in one tiny SC89–6 package.

### Features

- Max  $r_{DS(on)} = 0.5 \Omega$  at  $V_{GS} = 4.5 V$ ,  $I_D = -0.83 A$
- Max  $r_{DS(on)} = 0.7 \Omega$  at  $V_{GS} = 2.5 V$ ,  $I_D = -0.70 A$
- Max  $r_{DS(on)} = 1.2 \Omega$  at  $V_{GS} = 1.8 V$ ,  $I_D = -0.43 A$
- Max  $r_{DS(on)} = 1.8 \Omega$  at  $V_{GS} = 1.5 V$ ,  $I_D = -0.36 A$
- Control MOSFET (Q1) Includes Zener Protection for ESD Ruggedness (>4 kV Human Body Model)
- High Performance Trench Technology for Extremely Low r<sub>DS(on)</sub>
- Compact Industry Standard SC89-6 Surface Mount Package
- This Device is Pb-Free and is RoHS Compliant

## Applications

- Power Management
- Load Switch

#### **MOSFET MAXIMUM RATINGS** $T_A = 25^{\circ}C$ Unless Otherwise Noted

Symbol	Parameter	Rating	Units
Vin	Gate to Source Voltage (Q2)	±8	V
Von/off	Gate to Source Voltage (Q1)	–0.5 to 8	V
ILoad	Load Current -Continuous (Note 2)	0.83	А
	-Pulsed (Note 2)	1.0	
P <sub>D</sub>	Power Dissipation (Note 1a)	0.625	W
	Power Dissipation (Note 1b)	0.446	
TJ, TSTG	Operating and Storage Junction Temperature Range	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# THERMAL CHARACTERISTICS

Symbol	Parameter	Rating	Units
Reja	Thermal Resistance, Junction to Ambient (Note 1a)	200	°C/W
Reja	Thermal Resistance, Junction to Ambient (Note 1b)	280	



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See Application Circuit



MARKING DIAGRAM



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### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

# FDY6342L

#### PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
Н	FDY6342L	SC89-6	7"	8 mm	3000 units

#### **ELECTRICAL CHARACTERISTICS** $T_J = 25^{\circ}C$ , Unless Otherwise Noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
OFF CHAR	ACTERISTICS						
BVIN	V <sub>IN</sub> Breakdown Voltage	$I_D = -250 \ \mu\text{A}, \ V_{ON/OFF} = 0 \ V$	8			V	
I <sub>Load</sub>	Zero Gate Voltage Drain Current	V <sub>IN</sub> =6.4 V, V <sub>ON/OFF</sub> = 0 V			-1	μΑ	
I <sub>FL</sub>	Leakage Current, Forward	V <sub>IN</sub> = 8 V, V <sub>ON/OFF</sub> = 0 V			10	μΑ	
I <sub>RL</sub>	Leakage Current, Reverse	$V_{IN} = -8 V$ , $V_{ON/OFF} = 0 V$			-10	μΑ	
ON CHARA	ON CHARACTERISTICS						
V <sub>ON/OFF(th)</sub>	Gate Threshold Voltage	$V_{IN} = V_{ON/OFF}$ , $I_D = -250 \ \mu A$	0.65	0.85	1.5	V	
r <sub>DS(on)</sub>	Static Drain to Source On Resistance (Q2)	$V_{IN} = 4.5 \text{ V}, I_D = -0.83 \text{ A}$		0.28	0.5	Ω	
		V <sub>IN</sub> = 2.5 V, I <sub>D</sub> = -0.70 A		0.35	0.7		
		V <sub>IN</sub> = 1.8 V, I <sub>D</sub> = -0.43 A		0.45	1.2		
		V <sub>IN</sub> = 1.5 V, I <sub>D</sub> = -0.36 A		0.57	1.8		
	Static Drain to Source On Resistance (Q1)	$V_{IN} = 4.5 \text{ V}, I_D = 0.4 \text{ A}$		2.9	4.0	1	
		$V_{IN} = 2.7 \text{ V}, I_D = 0.2 \text{ A}$		3.5	5.0	1	

#### DRAIN-SOURCE DIODE CHARACTERISTICS

I <sub>S</sub>	Maximum Continuous Drain to Source Diode Forward Current			-0.25	Α
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	V <sub>ON/OFF</sub> = 0 V, I <sub>S</sub> = -0.25 A (Note 2)	-0.8	-1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. R<sub>0JA</sub> is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0JC</sub> is guaranteed by design while R<sub>0JA</sub> is determined by the user's board design.



a) 200°C/W when mounted on a 1 in<sub>2</sub> pad of 2 oz copper.



b) 280°C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300  $\mu s,$  Duty cycle < 2.0%.

# FDY6342L Load Switch Application Circuit



External Component Recommendation:

For additional in-rush current control, R2 and C1 can be added. For more information, see application note AN1030.

# FDY6342L

#### TYPICAL CHARACTERISTICS T<sub>J</sub> = 25°C, Unless Otherwise Noted



Figure 1. Conduction Voltage Drop Variation with Load Current



Figure 3. Conduction Voltage Drop Variation with Load Current



Figure 5. On–Resistance Variaton with Input Current



Figure 2. Conduction Voltage Drop Variation with Load Current



Figure 4. Conduction Voltage Drop Variation with Load Current





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